

HAT2203C

Silicon N Channel MOS FET
Power Switching

R07DS0323EJ0600

Rev.6.00

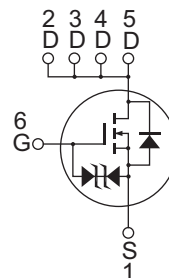
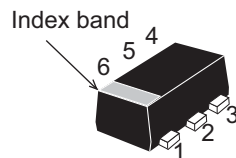
Mar 19, 2014

Features

- Low on-resistance
 $R_{DS(on)} = 69 \text{ m}\Omega$ typ.(at $V_{GS} = 4.5 \text{ V}$)
- Low drive current
- High density mounting
- 2.5 V gate drive device

Outline

RENESAS Package code: PWSF0006JA-A
(Package name: CMFPAK - 6)



1. Source
2. Drain
3. Drain
4. Drain
5. Drain
6. Gate

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	20	V
Gate to Source voltage	V_{GSS}	± 12	V
Drain current	I_D	2	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	8	A
Body - Drain diode reverse Drain current	I_{DR}	2	A
Channel dissipation	P_{ch} ^{Note2}	830	mW
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. When using the glass epoxy board (FR4 40 x 40 x 1.6mm)

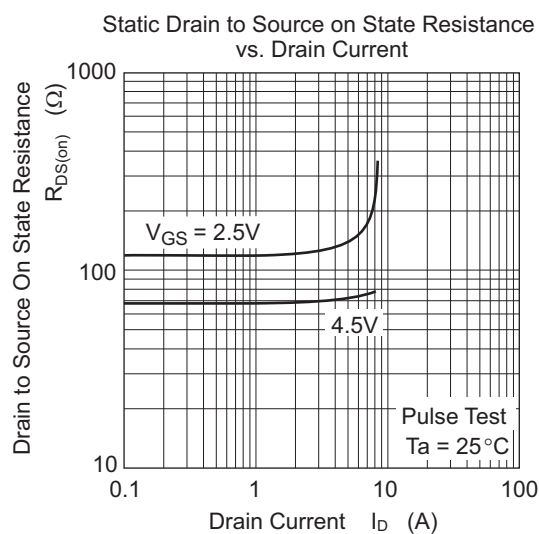
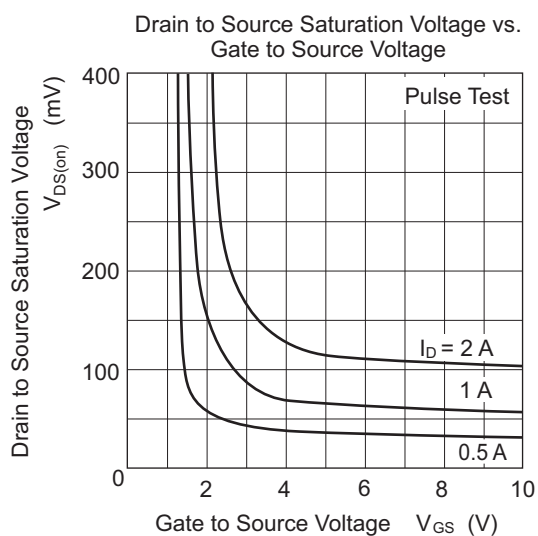
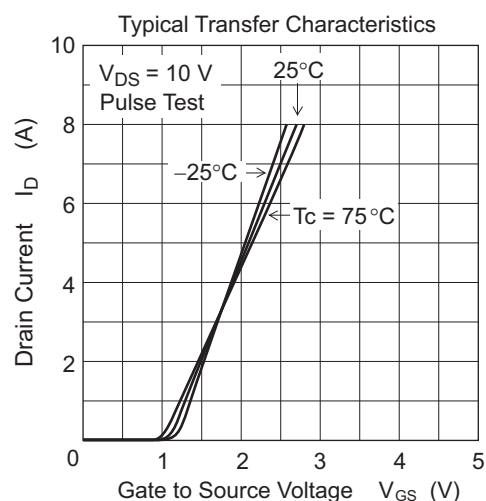
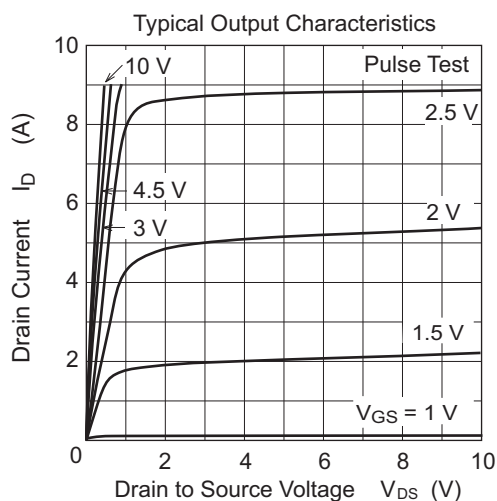
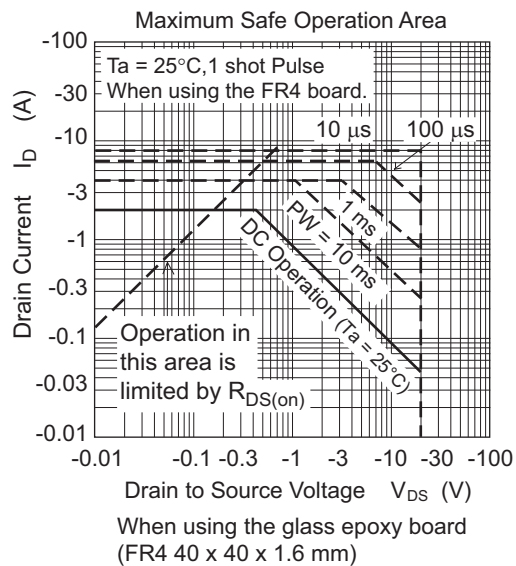
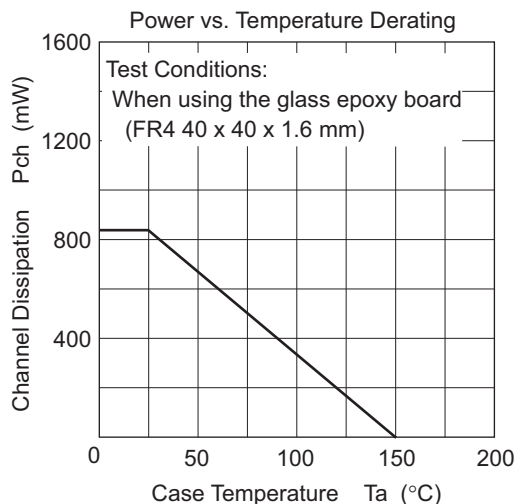
Electrical Characteristics

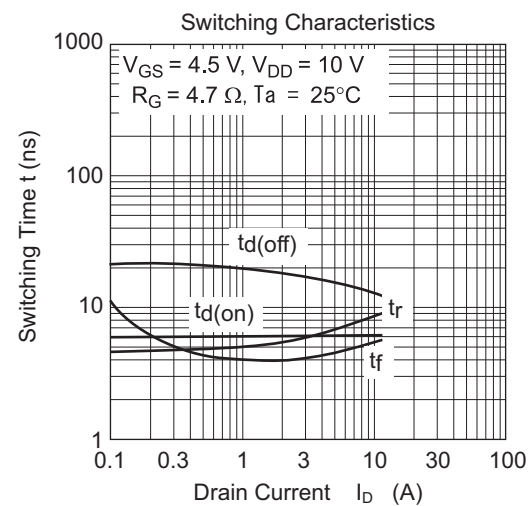
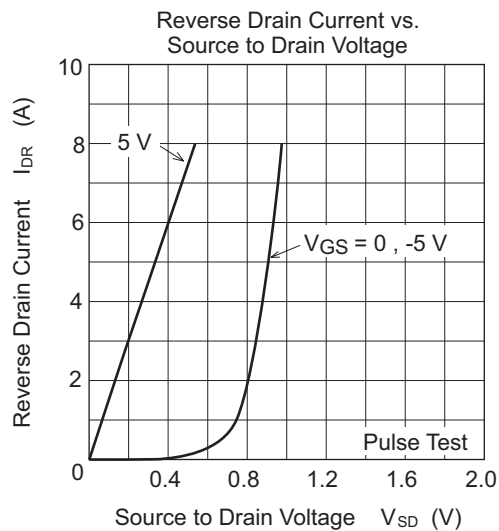
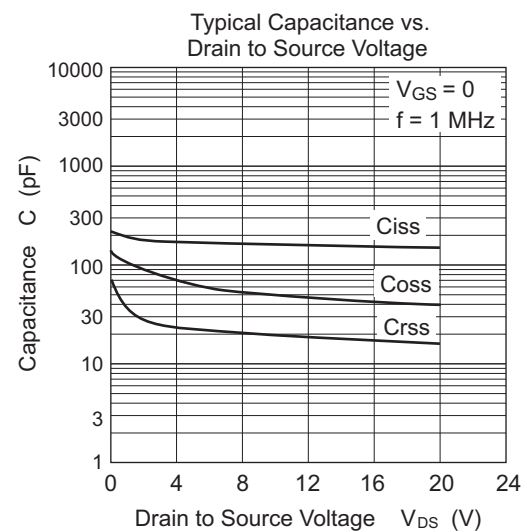
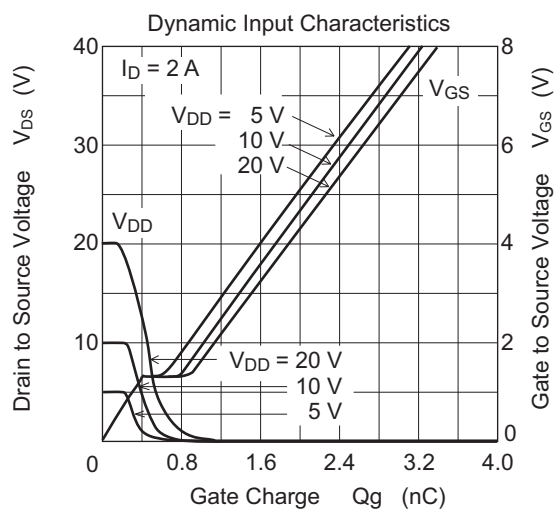
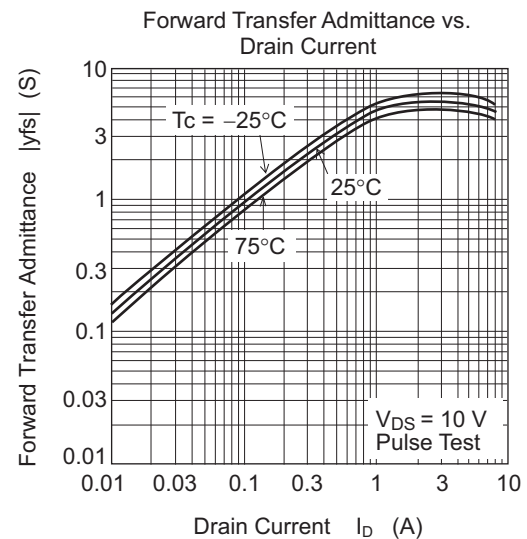
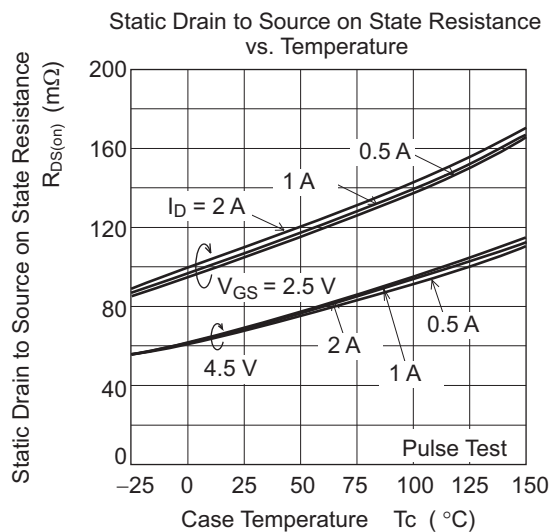
(Ta = 25°C)

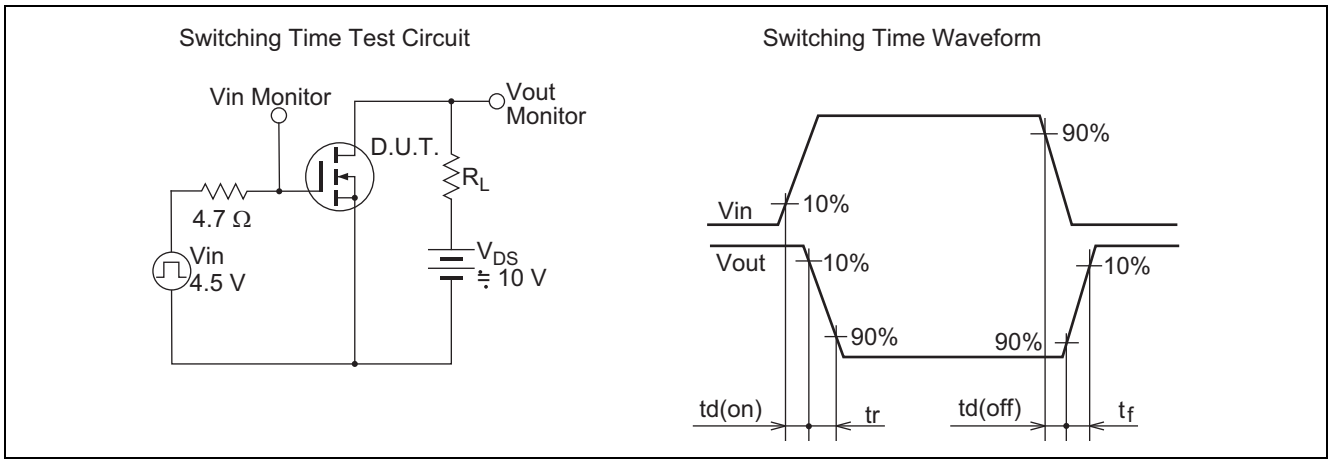
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	20	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to Source breakdown voltage	$V_{(BR)GSS}$	± 12	—	—	V	$I_G = \pm 100 \mu\text{A}$, $V_{DS} = 0$
Gate to Source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 10 \text{ V}$, $V_{DS} = 0$
Drain to Source leak current	I_{DSS}	—	—	1	μA	$V_{DS} = 20 \text{ V}$, $V_{GS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	0.4	—	1.4	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Drain to Source on state resistance	$R_{DS(on)}$	—	69	90	$\text{m}\Omega$	$I_D = 1 \text{ A}$, $V_{GS} = 4.5 \text{ V}$ ^{Note3}
	$R_{DS(on)}$	—	107	150	$\text{m}\Omega$	$I_D = 1 \text{ A}$, $V_{GS} = 2.5 \text{ V}$ ^{Note3}
Forward transfer admittance	$ y_{fs} $	3	4.5	—	S	$I_D = 1 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note3}
Input capacitance	C_{iss}	—	165	—	pF	$V_{DS} = 10 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	50	—	pF	
Reverse transfer capacitance	C_{rss}	—	20	—	pF	
Turn - on delay time	$t_{d(on)}$	—	6	—	ns	$I_D = 1 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 10 \Omega$ $R_g = 4.7 \Omega$
Rise time	t_r	—	5	—	ns	
Turn - off delay time	$t_{d(off)}$	—	20	—	ns	
Fall time	t_f	—	4	—	ns	
Total Gate charge	Q_g	—	1.8	—	nC	$V_{DD} = 10 \text{ V}$ $V_{GS} = 4.5 \text{ V}$ $I_D = 2 \text{ A}$
Gate to Source charge	Q_{gs}	—	0.4	—	nC	
Gate to Drain charge	Q_{gd}	—	0.4	—	nC	
Body - Drain diode forward voltage	V_{DF}	—	0.8	1.1	V	$I_F = 2 \text{ A}$, $V_{GS} = 0$ ^{Note3}

Notes: 3. Pulse test

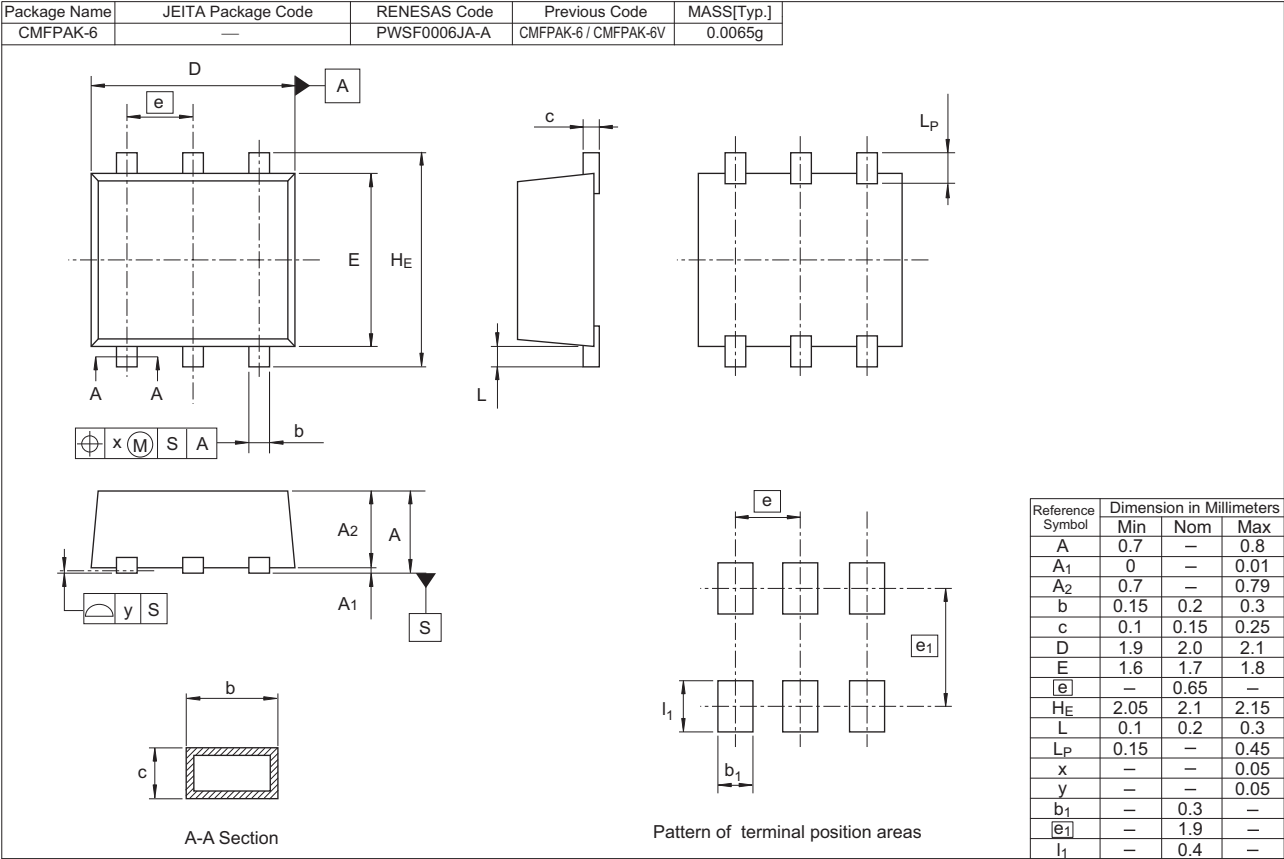
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HAT2203C-EL-E	3000 pcs	Taping

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